4V Drive Pch MOSFET RSR020P03

●Structure

Silicon P-channel MOSFET

● Features

- 1) Low On-resistance
- 2) Space saving-small surface mount package (TSMT3)
- 3) 4V drive

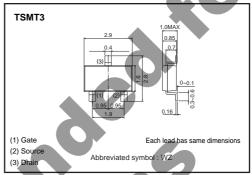
Applications

Switching

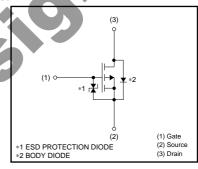
Packaging specifications

Туре	Package	Taping		
	Code	TL		
	Basic ordering unit (pieces)	3000		
RSR020P03		0		

● Dimensions (Unit: mm)



•Inner circuit



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V _{DSS}	-30	V
Gate-source voltage		V _{GSS}	±20	V
Drain current	Continuous	ID	±2	Α
	Pulsed	I _{DP} *1	±8	А
Source current (Body diode)	Continuous	Is	-0.8	Α
	Pulsed	I _{SP} *1	-8	Α
Total power dissipation		P _D *2	1	W
Channel temperature		Tch	150	°C
Range of storage temperature	Tstg	-55 to +150	°C	

^{*1} Pw≤10μs, Duty cycle≤1%

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	125	°C/W

^{*} Mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	_	-	±10	μА	Vgs=±20V, Vps=0V
Drain-source breakdown voltage	V _{(BR) DSS}	-30	_	_	V	I _D = -1mA, V _{GS} =0V
Zero gate voltage drain current	IDSS	_	_	-1	μА	V _{DS} = -30V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	-1.0	_	-2.5	V	V _{DS} = -10V, I _D = -1mA
Static drain-source on-state resistance		_	85	120	mΩ	I _D = -2A, V _G S= -10V
	R _{DS (on)} *	_	135	190	mΩ	I _D = -1A, V _G S= -4.5V
		_	150	210	mΩ	I _D = -1A, V _G = -4V
Forward transfer admittance	Y _{fs} *	1.4	_	_	S	V _{DS} = -10V, I _D = -1A
Input capacitance	Ciss	_	370	_	pF	V _{DS} = -10V
Output capacitance	Coss	_	80	_	pF	Vgs=0V
Reverse transfer capacitance	Crss	_	55	_	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	_	8	_	ns	V _{DD} ≒ –15V
Rise time	tr *	_	10	_	ns	ID= -1A
Turn-off delay time	td (off) *	_	35	_	ns	Vgs= - 10V RL=15Ω
Fall time	t _f *	_	11	_	ns	R _G =10Ω
Total gate charge	Qg *	_	4.3	_	nC	V _{DD} ≒-15V V _{GS} =-5V
Gate-source charge	Q _{gs} *	-	1.4	_	nC	I _D =-2A
Gate-drain charge	Q _{gd} *	-	1.5	-	nC	RL= 7.5Ω Rg= 10Ω

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

●Body diode characteris Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Forward voltage	Vsp*	- IVIII 1.	тур. —	-1.2	V	Is= -0.8A, V _{GS} =0V	
Pulsed	Vsp			-1.2		Is= -0.8A, Vos=0V	



•Electrical characteristics curves

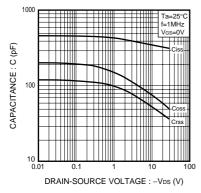


Fig.1 Typical Capacitance vs. Drain-Source Voltage

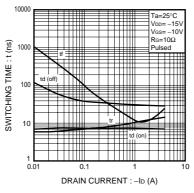


Fig.2 Switching Characteristics

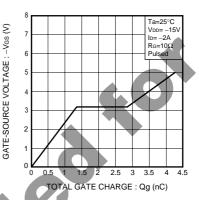


Fig.3 Dynamic Input Characteristics

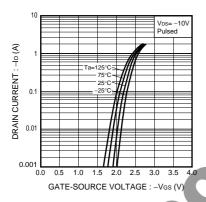


Fig.4 Typical Transfer Characteristics

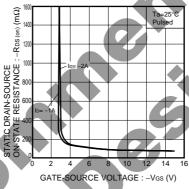


Fig.5 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

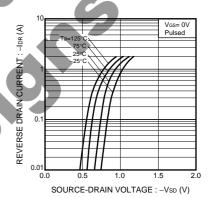
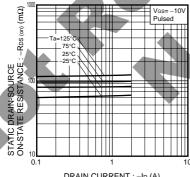
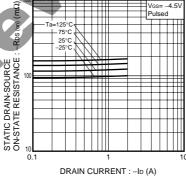


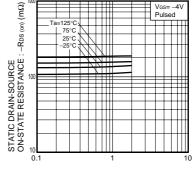
Fig.6 Reverse Drain Current vs. Source-Drain Voltage



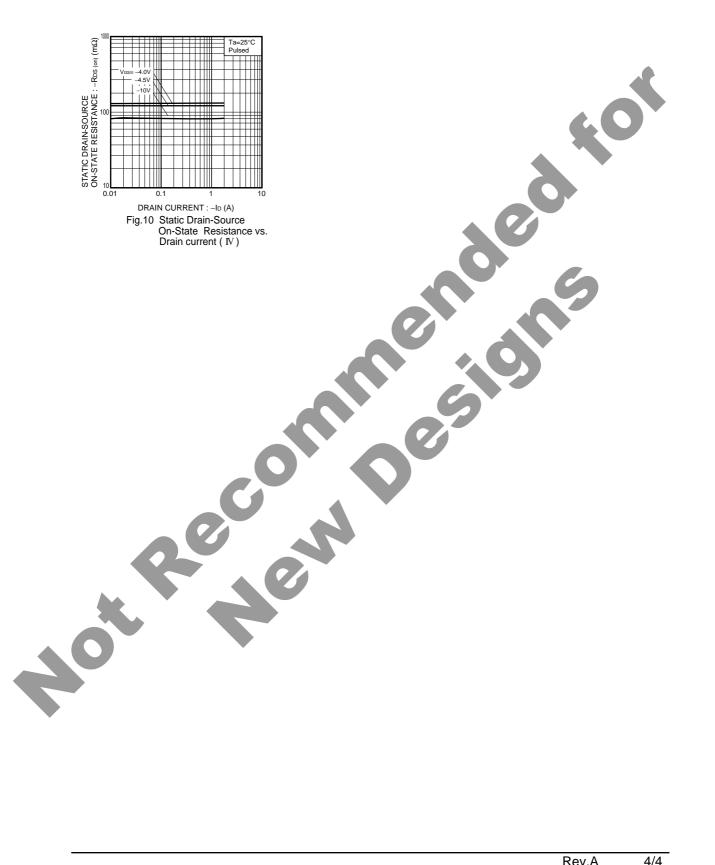
DRAIN CURRENT : -ID (A)
Fig.7 Static Drain-Source
On-State Resistance vs.
Drain current (I)



DRAIN CURRENT: -ID (A)
Fig.8 Static Drain-Source
On-State Resistance vs.
Drain current (II)



DRAIN CURRENT : -ID (A)
Fig.9 Static Drain-Source
On-State Resistance vs.
Drain current (III)



Notes

- 1) The information contained herein is subject to change without notice.
- Before you use our Products, please contact our sales representative and verify the latest specifications:
- 3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors.

 Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM.
- 4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
- 5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
- 6) The Products are intended for use in general electronic equipment (i.e. AV/OA devices, communication, consumer systems, gaming/entertainment sets) as well as the applications indicated in this document.
- 7) The Products specified in this document are not designed to be radiation tolerant.
- 8) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative: transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.
- Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
- 10) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
- 11) ROHM has used reasonable care to ensur the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
- 12) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
- 13) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
- 14) This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ROHM Semiconductor: